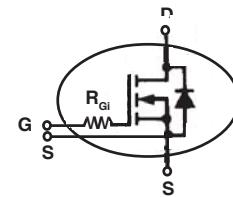


**LinearL2™**  
**Power MOSFET**  
**w/ Extended FBSOA**

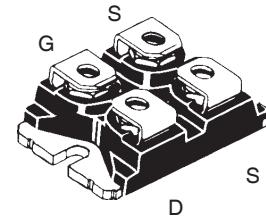
**IXTN80N30L2**

N-Channel Enhancement Mode  
Avalanche Rated



**V<sub>DSS</sub>** = 300V  
**I<sub>D25</sub>** = 80A  
**R<sub>DS(on)</sub>** ≤ 38mΩ

miniBLOC, SOT-227  
 E153432



G = Gate      D = Drain  
S = Source

Symbol	Test Conditions	Maximum Ratings		
V <sub>DSS</sub>	T <sub>J</sub> = 25°C to 150°C	300		V
V <sub>DGR</sub>	T <sub>J</sub> = 25°C to 150°C, R <sub>GS</sub> = 1MΩ	300		V
V <sub>GSS</sub>	Continuous	±20		V
V <sub>GSM</sub>	Transient	±30		V
I <sub>D25</sub>	T <sub>C</sub> = 25°C	80		A
I <sub>DM</sub>	T <sub>C</sub> = 25°C, Pulse Width Limited by T <sub>JM</sub>	200		A
I <sub>A</sub>	T <sub>C</sub> = 25°C	80		A
E <sub>AS</sub>	T <sub>C</sub> = 25°C	3		J
P <sub>D</sub>	T <sub>C</sub> = 25°C	735		W
T <sub>J</sub>		-55 ... +150		°C
T <sub>JM</sub>		150		°C
T <sub>stg</sub>		-55 ... +150		°C
V <sub>ISOL</sub>	50/60 Hz, RMS	2500		V~
	I <sub>ISOL</sub> ≤ 1mA	3000		V~
M <sub>d</sub>	Mounting Torque	1.5/13	Nm/lb.in	
	Terminal Connection Torque	1.3/11.5	Nm/lb.in	
Weight		30		g

Symbol	Test Conditions (T <sub>J</sub> = 25°C, Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
BV <sub>DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 1mA	300		V
V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 3mA	2.5		V
I <sub>GSS</sub>	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V			±200 nA
I <sub>DSS</sub>	V <sub>DS</sub> = V <sub>DSS</sub> , V <sub>GS</sub> = 0V			10 μA
	T <sub>J</sub> = 125°C			250 μA
R <sub>DS(on)</sub>	V <sub>GS</sub> = 10V, I <sub>D</sub> = 0.5 • I <sub>D25</sub> , Note 1	30	38	mΩ

**Features**

- International Standard Package
- miniBLOC, with Aluminium Nitride Isolation
- Isolation Voltage 2500V~
- High Current Handling Capability
- Avalanche Rated
- Low R<sub>DS(on)</sub>
- Designed for Linear Operation
- Guaranteed FBSOA at 75°C

**Advantages**

- Easy to Mount
- Space Savings
- High Power Density

**Applications**

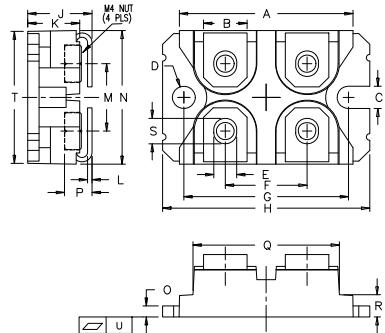
- Solid State Circuit Breakers
- Soft Start Controls
- Linear Amplifiers
- Programmable Loads
- Current Regulators

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
$I_{fs}$	$V_{DS} = 10\text{V}$ , $I_D = 0.5 \cdot I_{D25}$ , Note 1	24	36	48 S
$C_{iss}$	$V_{GS} = 0\text{V}$ , $V_{DS} = 25\text{V}$ , $f = 1\text{MHz}$	19.1		nF
$C_{oss}$		1760		pF
$C_{rss}$		490		pF
$R_{Gi}$	Integrated Gate Input Resistor	0.88		$\Omega$
$t_{d(on)}$	$V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$ $R_G = 1\Omega$ (External)	40		ns
$t_r$		180		ns
$t_{d(off)}$		174		ns
$t_f$		67		ns
$Q_{g(on)}$	$V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 0.5 \cdot I_{D25}$	660		nC
$Q_{gs}$		107		nC
$Q_{gd}$		364		nC
$R_{thJC}$			0.17 $^\circ\text{C}/\text{W}$	
$R_{thCS}$		0.05		$^\circ\text{C}/\text{W}$

### Safe Operating Area Specification

Symbol	Test Conditions	Characteristic Values		
		Min.	Typ.	Max.
SOA	$V_{DS} = 300\text{V}$ , $I_D = 1.47\text{A}$ , $T_c = 75^\circ\text{C}$ , $T_p = 5\text{s}$	440		W

### SOT-227B (IXTN) Outline



(M4 screws (4x) supplied)

SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.240	1.255	31.50	31.88
B	.307	.323	7.80	8.20
C	.161	.169	4.09	4.29
D	.161	.169	4.09	4.29
E	.161	.169	4.09	4.29
F	.587	.595	14.91	15.11
G	1.186	1.193	30.12	30.30
H	1.496	1.505	38.00	38.23
J	.460	.481	11.68	12.22
K	.351	.378	8.92	9.60
L	.030	.033	0.76	0.84
M	.496	.506	12.60	12.85
N	.990	1.001	25.15	25.42
O	.078	.084	1.98	2.13
P	.195	.235	4.95	5.97
Q	1.045	1.059	26.54	26.90
R	.155	.174	3.94	4.42
S	.186	.191	4.72	4.85
T	.968	.987	24.59	25.07
U	-.002	.004	-0.05	0.1

### Source-Drain Diode

Symbol	Test Conditions	Characteristic Values		
	( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)	Min.	Typ.	Max.
$I_s$	$V_{GS} = 0\text{V}$		80	A
$I_{sm}$	Repetitive, pulse Width Limited by $T_{JM}$		320	A
$V_{SD}$	$I_F = I_S$ , $V_{GS} = 0\text{V}$ , Note 1		1.4	V
$t_{rr}$	$I_F = 40\text{A}$ , $dI/dt = 100\text{A}/\mu\text{s}$ $V_R = 100\text{V}$	485		ns
$Q_{RM}$		10		$\mu\text{C}$
$I_{RM}$		42		A

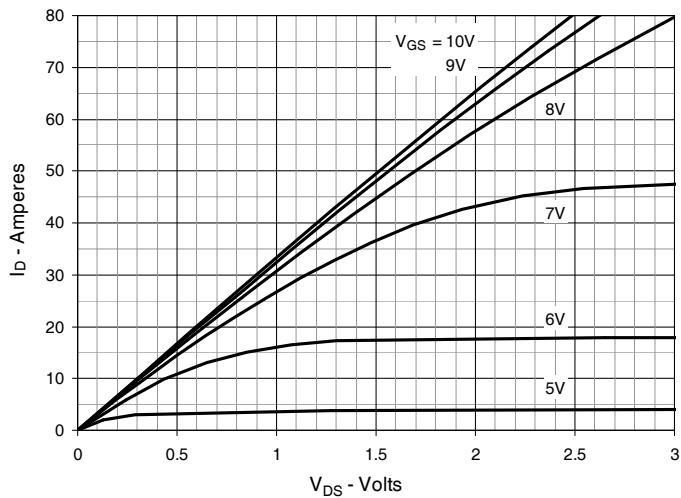
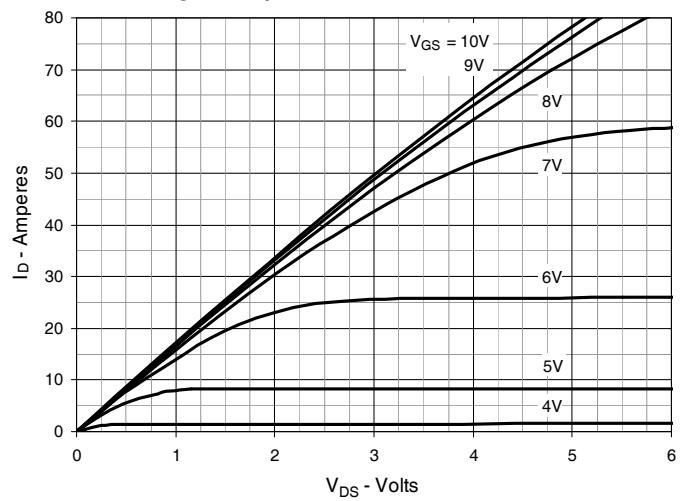
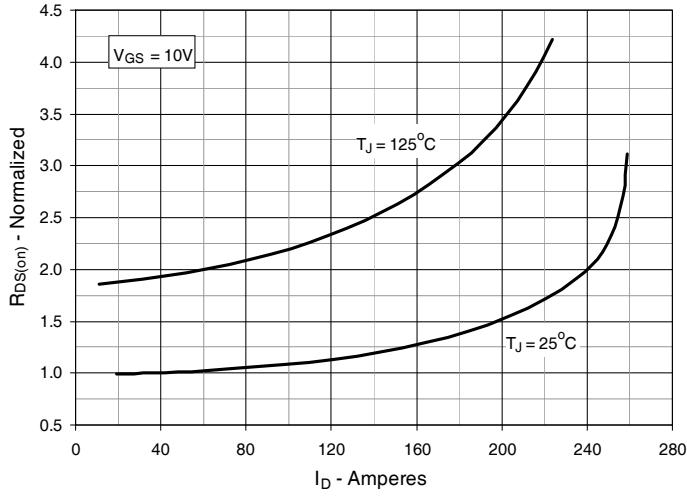
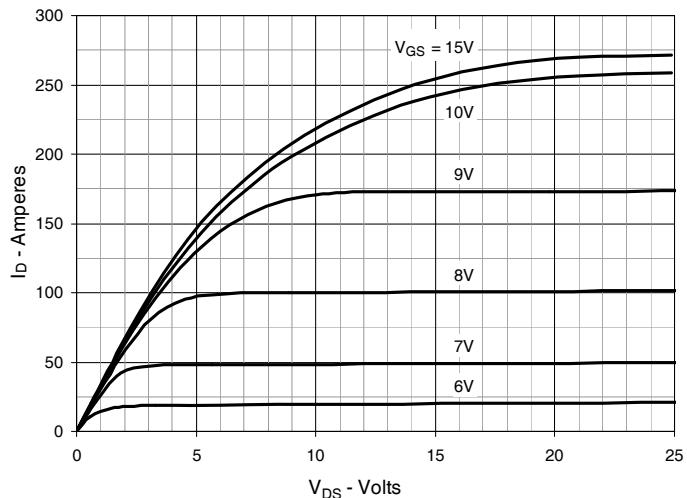
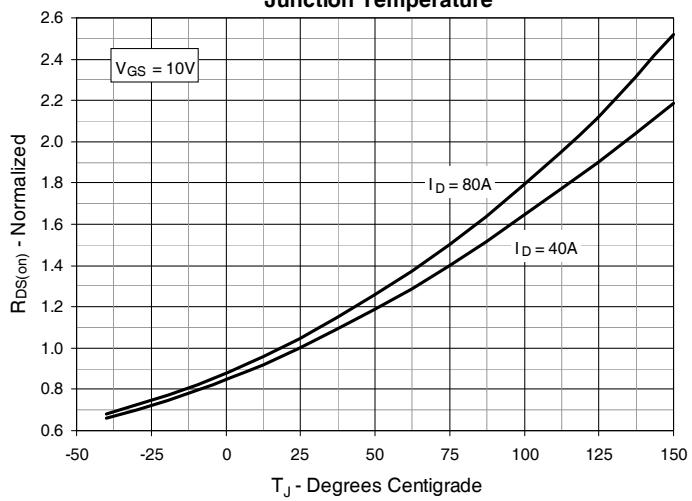
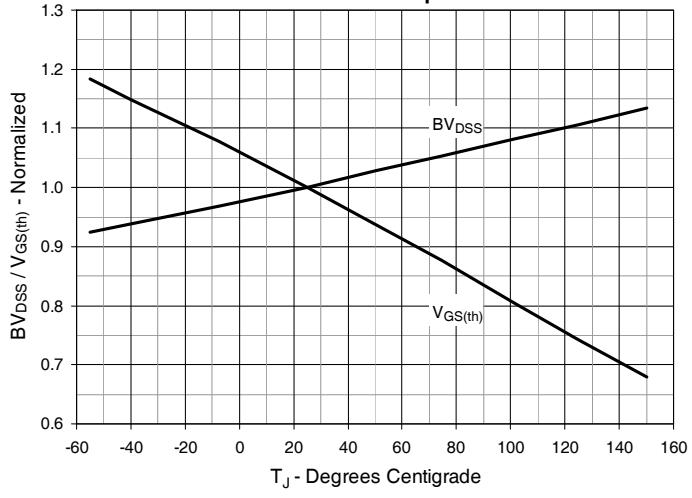
Note 1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .

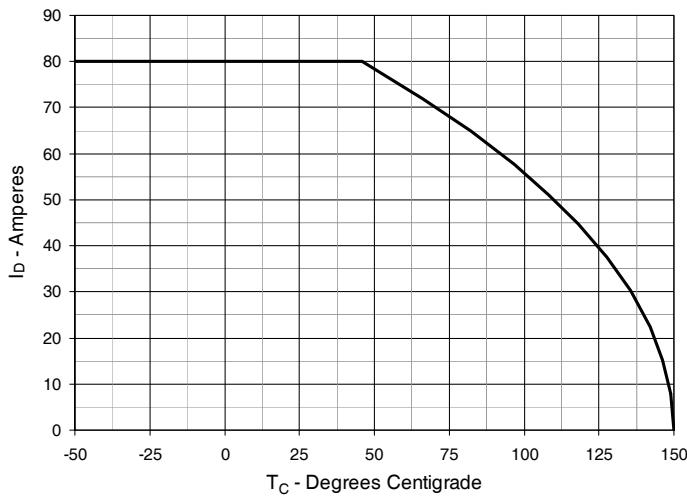
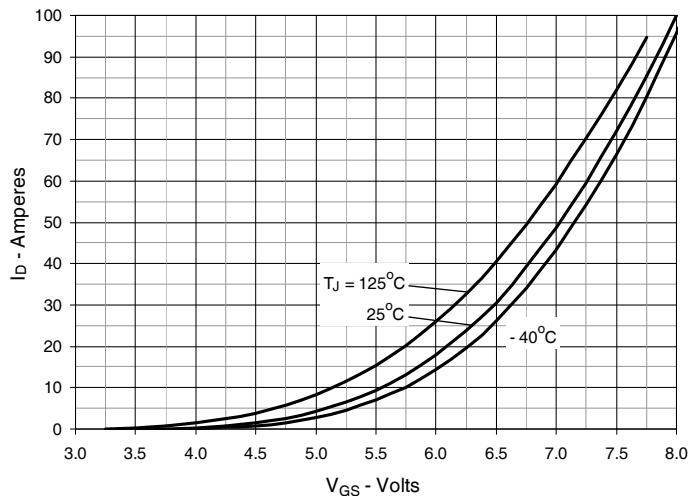
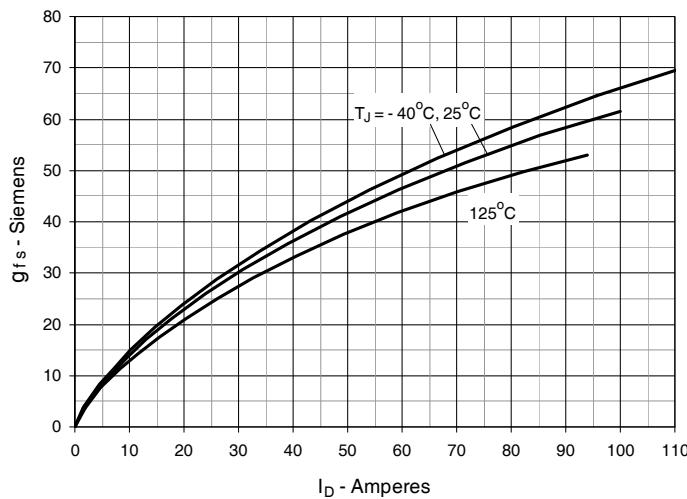
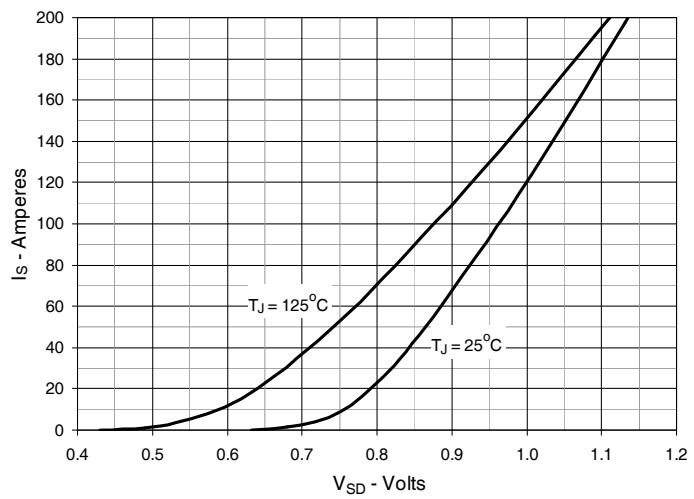
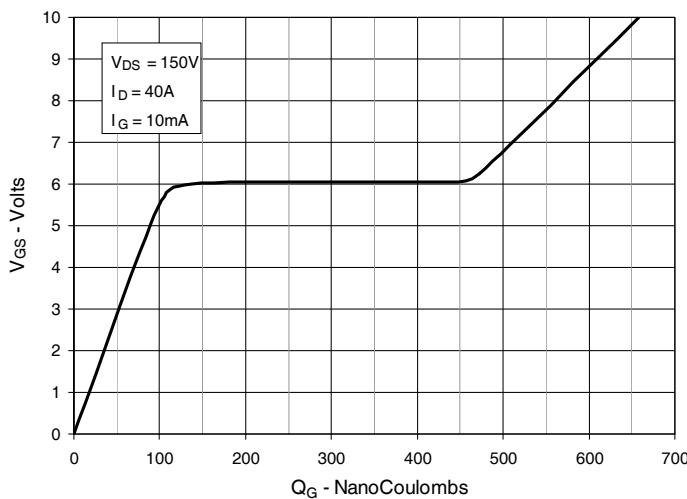
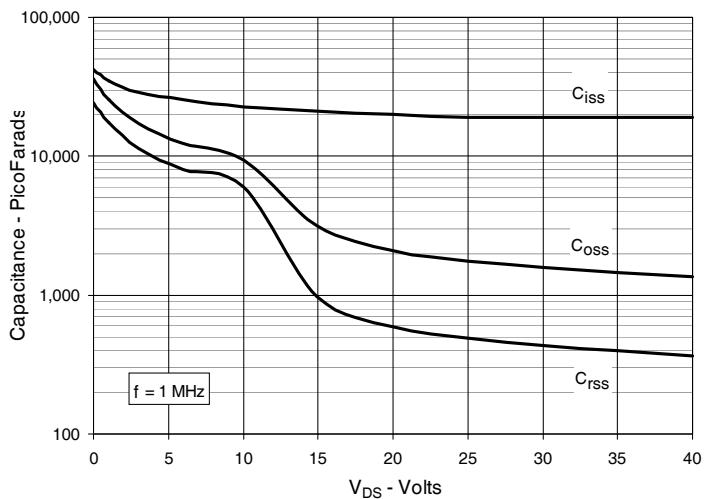
### ADVANCE TECHNICAL INFORMATION

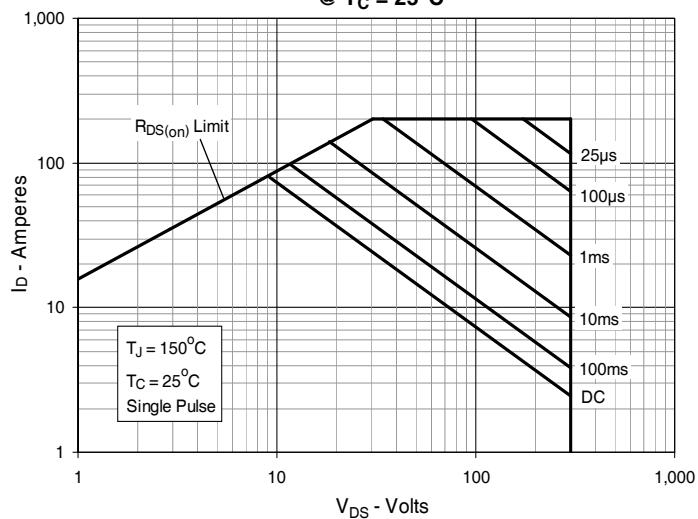
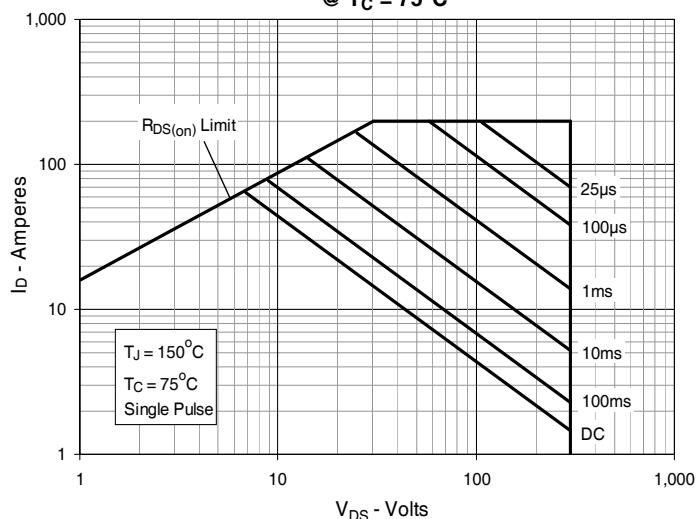
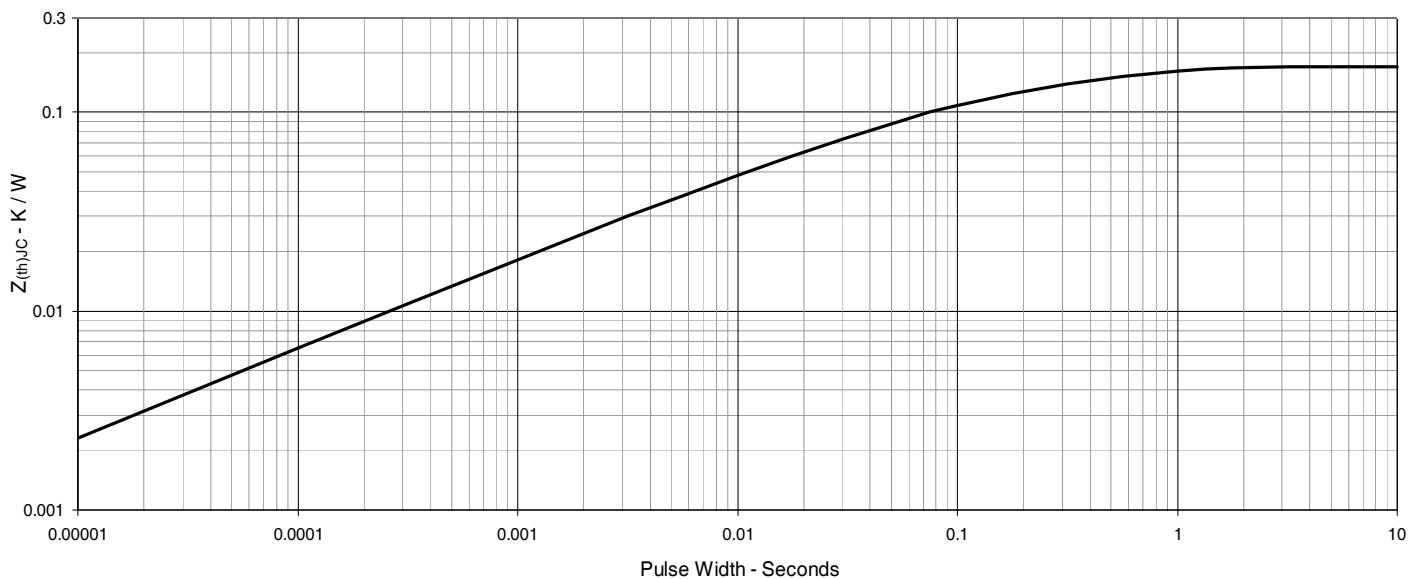
The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: 4,835,592 4,931,844 5,049,961 5,237,481 6,162,665 6,404,065B1 6,683,344 6,727,585 7,005,734B2 7,157,338B2 4,860,072 5,017,508 5,063,307 5,381,025 6,259,123B1 6,534,343 6,710,405B2 6,759,692 7,063,975B2 4,881,106 5,034,796 5,187,117 5,486,715 6,306,728B1 6,583,505 6,710,463 6,771,478B2 7,071,537

**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$** **Fig. 3. Output Characteristics @  $T_J = 125^\circ\text{C}$** **Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 40\text{A}$  Value vs. Drain Current****Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$** **Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 40\text{A}$  Value vs. Junction Temperature****Fig. 6. Normalized Breakdown & Threshold Voltages vs. Junction Temperature**

**Fig. 7. Maximum Drain Current vs. Case Temperature****Fig. 8. Input Admittance****Fig. 9. Transconductance****Fig. 10. Forward Voltage Drop of Intrinsic Diode****Fig. 11. Gate Charge****Fig. 12. Capacitance**

**Fig. 13. Forward-Bias Safe Operating Area**@  $T_C = 25^\circ\text{C}$ **Fig. 14. Forward-Bias Safe Operating Area**@  $T_C = 75^\circ\text{C}$ **Fig. 15. Maximum Transient Thermal Impedance**



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